

## 1.5A, 1000V Fast avalanche Surface Mount Rectifier

#### **FEATURES**

- Glass passivated junction chip
- Ideal for automated placement
- Fast switching for high efficiency
- High surge current capability
- Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- Halogen-free according to IEC 61249-2-21



**DO-214AC (SMA)** 





### **TYPICAL APPLICATION**

The superior avalanche capability of BYG21M is specially suited for free-wheeling, clamping, snubber, demagnetization in power supplies and other power switching applications.

#### **MECHANICAL DATA**

Case: DO-214AC (SMA)

Molding compound: UL flammability classification rating 94V-0 Moisture sensitivity level (MSL): level 1, per J-STD-020 Part no. with suffix "H" means AEC-Q101 qualified

Packing code with suffix "G" means green compound (halogen-free) **Terminal:** Matte tin plated leads, solderable per JESD22-B102

Meet JESD 201 class 2 whisker test **Polarity:** Indicated by cathode band **Weight:** 64 mg (approximately)

PARAMETER	SYMBOL	BYG21M	UNIT	
Maximum repetitive peak reverse voltage	$V_{RRM}$	1000	V	
Maximum RMS voltage	$V_{RMS}$	700	V	
Maximum DC blocking voltage	V <sub>DC</sub>	1000		
Maximum average forward rectified current	I <sub>F(AV)</sub>	1.5	А	
Peak forward surge current, 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	50	А	
Maximum instantaneous forward voltage $I_F$ =1A (Note 1) $I_F$ =1.5A	V <sub>F</sub>	1.5 1.6	V	
$T_J$ =25°C  Maximum reverse current @ Rated $V_R$ $T_J$ =125°C $T_J$ =125°C	I <sub>R</sub>	1 10 50	μА	
Pulse energy in avalanche mode, non repetitive (Inductive load switch off ) T <sub>A</sub> =25°C, I <sub>(BR)R</sub> =1.23A	E <sub>RSM</sub>	30	mJ	
Maximum reverse recovery time (Note 2)	t <sub>rr</sub>	120	ns	
Typical junction capacitance (Note 3)	CJ	13	pF	
Typical thermal resistance	$R_{ heta JA}$	20 70	°C/W	
Operating junction temperature range	T <sub>.l</sub>	- 55 to +150	°C	
Storage temperature range	T <sub>STG</sub>	- 55 to +150	°C	

Note 1: Pulse test with PW=300 $\mu$ s, 1% duty cycle Note 2: Test conditions:  $I_F$ =0.5A,  $I_R$ =1.0A,  $I_{RR}$ =0.25A

Note 3: Measured at 1 MHz and applied reverse voltage of 4.0V





ORDERING INFORMATION					
PART NO.	PART NO.	PACKING	PACKING CODE	PACKAGE	PACKING
PARTINO.	SUFFIX	CODE	SUFFIX		
BYG21M (Note 1)	R3		SMA	1,800 / 7" Plastic reel	
		R2		SMA	7,500 / 13" Paper reel
	M2	G	SMA	7,500 / 13" Plastic reel	
	F3		Folded SMA	1,800 / 7" Plastic reel	
		F2		Folded SMA	7,500 / 13" Paper reel
		F4		Folded SMA	7,500 / 13" Plastic reel

Note 1: Whole series with green compound

EXAMPLE					
EXAMPLE PART NO.	PART NO.	PART NO. SUFFIX	PACKING CODE	PACKING CODE SUFFIX	DESCRIPTION
BYG21MHR3G	BYG21M	Ħ	R3	G	AEC-Q101 qualified Green compound

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub>=25°C unless otherwise noted)

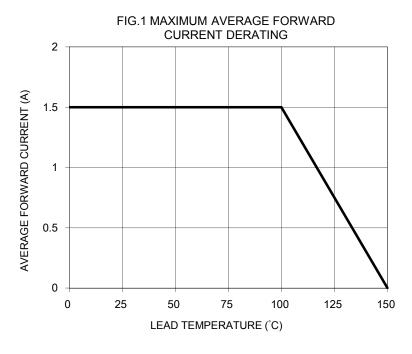


FIG. 2 TYPICAL REVERSE CHARACTERISTICS 100 INSTANTANEOUS REVERSE CURRENT(µA)  $T_J=125^{\circ}C$ 10 1 0.1  $T_J=25^{\circ}C$ 0.01 0 20 100 40 60 80 PERCENT OF RATED PEAK REVERSE VOLTAGE (%)

FIG. 3 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

50

40

8.3ms single half sine wave

10

10

NUMBER OF CYCLES AT 60 Hz

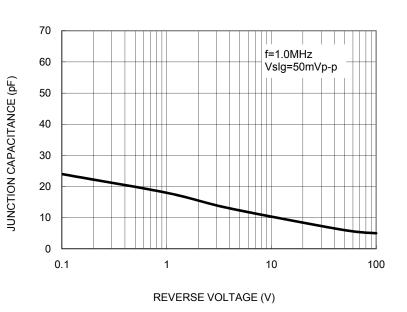
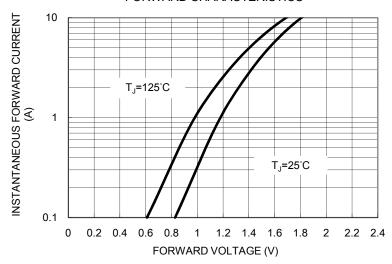


FIG. 4 TYPICAL JUNCTION CAPACITANCE

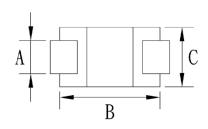
Version: A1601



FIG. 5 TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS



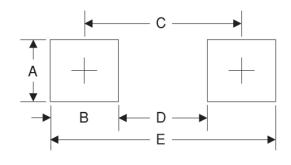
## PACKAGE OUTLINE DIMENSIONS DO-214AC (SMA)



Н	
	-
D	
EGA	
F	

DIM.	Unit (mm)		Unit (inch)	
Dilvi.	Min	Max	Min	Max
Α	1.27	1.58	0.050	0.062
В	4.06	4.60	0.160	0.181
С	2.29	2.83	0.090	0.111
D	1.99	2.50	0.078	0.098
Е	0.90	1.41	0.035	0.056
F	4.95	5.33	0.195	0.210
G	0.10	0.20	0.004	0.008
Н	0.15	0.31	0.006	0.012

## **SUGGESTED PAD LAYOUT**



Symbol	Unit (mm)	Unit (inch)
А	1.68	0.066
В	1.52	0.060
С	3.93	0.155
D	2.41	0.095
E	5.45	0.215

### **MARKING DIAGRAM**



P/N = Specific Device Code G = Green Compound

YW = Date Code F = Factory Code







#### **Notice**

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Version: A1601

# **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for Diodes - General Purpose, Power, Switching category:

Click to view products by Taiwan Semiconductor manufacturer:

Other Similar products are found below:

MCL4151-TR3 MMBD3004S-13-F RD0306T-H RD0506LS-SB-1H RGP30G-E373 DSE010-TR-E BAQ333-TR BAQ335-TR BAQ33-GS18 BAS1602VH6327XT BAV17-TR BAV19-TR BAV301-TR BAW27-TAP HSC285TRF-E NSVBAV23CLT1G NTE525 1SS181-TP 1SS184-TP 1SS193,LF 1SS193-TP 1SS400CST2RA SBAV99LT3G SDAA13 LL4448-GS18 SHN2D02FUTW1T1G LS4150GS18 LS4151GS08 SMMBD7000LT3G FC903-TR-E 1N4449 1N4934-E3/73 1SS226-TP APT100DL60HJ RFUH20TB3S RGP30G-E354 RGP30M-E3/73 D291S45T MCL4151-TR BAS 16-02V H6327 BAS 21U E6327 BAS 28 E6327 BAS33-TAP BAS 70-02V H6327 BAV300-TR BAV303-TR3 BAW27-TR BAW56DWQ-7-F BAW56M3T5G BAW75-TAP